

Super Fast Silicon Rectifiers
Reverse Voltage - 100 to 600 V
Forward Current - 5 A

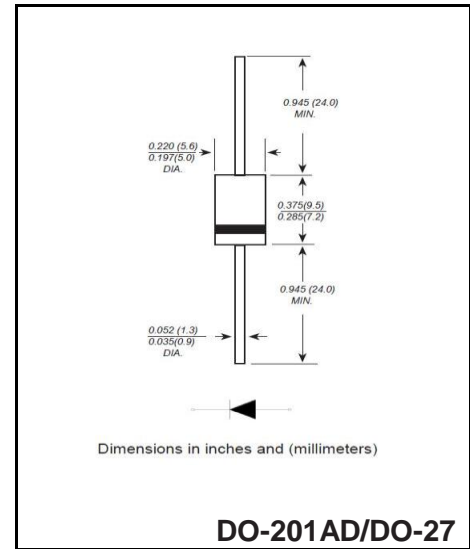
FEATURES

- ◆ For surface mounted applications
- ◆ Low profile package
- ◆ Glass Passivated Chip Junction
- ◆ Ideal for automated placement
- ◆ Lead free in comply with EU RoHS 2011/65/EU directives



MECHANICAL DATA

- ◆ Case: DO-201AD/DO-27
- ◆ Terminals: Solderable per MIL-STD-750, Method 2026
- ◆ Approx. Weight: 0.98g / 0.0345oz



Maximum Ratings and Electrical characteristics

Ratings at 25 °C ambient temperature unless otherwise specified.
 Single phase half-wave 60 Hz, resistive or inductive load, for capacitive load current derate by 20 %.

Parameter	Symbols	SF52G	SF53G	SF54G	SF56G	SF57G	SF58G	Units
Maximum Repetitive Peak Reverse Voltage	V_{RRM}	100	150	200	400	500	600	V
Maximum RMS voltage	V_{RMS}	70	105	140	280	350	420	V
Maximum DC Blocking Voltage	V_{DC}	100	150	200	400	500	600	V
Maximum Average Forward Rectified Current at $T_c = 100\text{ }^\circ\text{C}$	$I_{F(AV)}$	5.0						A
Peak Forward Surge Current 8.3 ms Single Half Sine Wave Superimposed on Rated Load	I_{FSM}	200.0						A
Maximum Instantaneous Forward Voltage at 5.0A	V_F	0.95		1.25		1.65		V
Maximum DC Reverse Current $T_a = 25\text{ }^\circ\text{C}$ at Rated DC Blocking Voltage $T_a = 125\text{ }^\circ\text{C}$	I_R	10 500						μA
Maximum reverse recovery time ^(Note 1)	T_{rr}	35						nS
Typical Junction Capacitance ^(Note 2)	C_j	78.0						pF
Typical Thermal Resistance	$R_{\theta JA}$	45.0						$^\circ\text{C/W}$
Operating and Storage Temperature Range	T_j, T_{stg}	-55 ~ +150						$^\circ\text{C}$

(1) Measured at 1 MHz and applied reverse voltage of 4 V D.C

(2) Reverse recovery time test condition: $I_F=0.5\text{A}$ $I_R=1.0\text{A}$ $I_{rr}=0.25\text{A}$

Ratings And Characteristic Curves

FIG. 1- DERATING CURVE OUTPUT RECTIFIED CURRENT

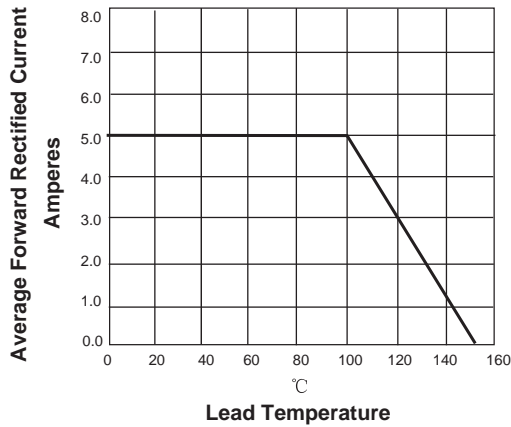


FIG. 2-MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT PER LEG

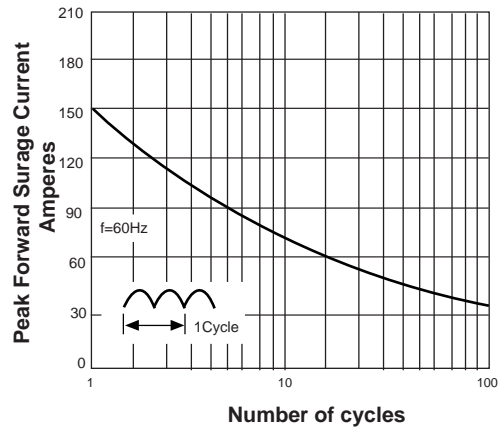


FIG. 3-TYPICAL FORWARD VOLTAGE CHARACTERISTICS

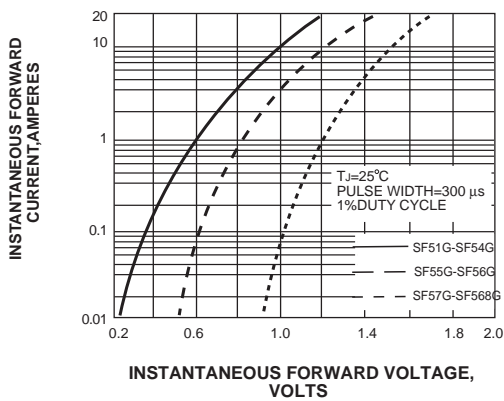
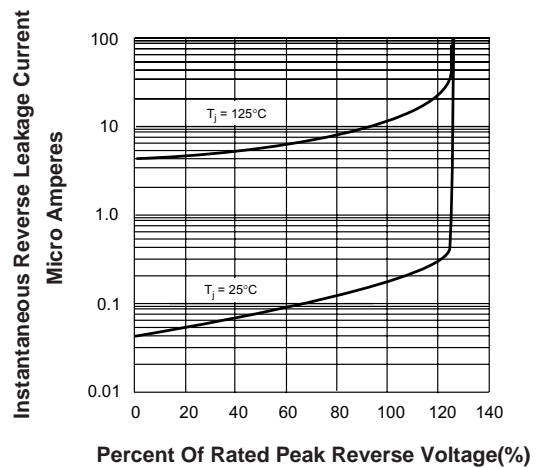
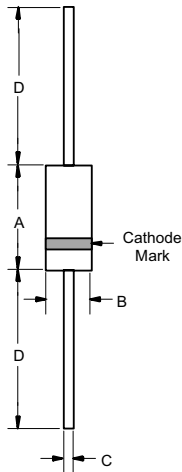


FIG. 4-TYPICAL REVERSE LEAKAGE CHARACTERISTICS



Package Outline DO-201AD(DO-27)



DIMENSIONS					
DIM	INCHES		MM		NOTE
	MIN	MAX	MIN	MAX	
A	---	.370	---	9.50	
B	---	.250	---	6.40	
C	.048	.052	1.20	1.30	
D	1.000	---	25.40	---	

Summary of Packing Options

Package	Packing Description	Packing Quantity	Industry Standard
DO-201AD(DO-27)	BOX	250/1000/1250	EIA-481-1

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for [Rectifiers](#) category:

Click to view products by [YFW Electronics](#) manufacturer:

Other Similar products are found below :

[70HFR40](#) [FR105 R0](#) [RL252-TP](#) [1N5397](#) [1N4005-TR](#) [1N4007-BP](#) [UFS120Je3/TR13](#) [20ETS12S](#) [RRE02VS6SGTR](#) [MS306](#) [A1N5404G-G](#)
[CRF02\(T5L,TEMQ\)](#) [ACGRB207-HF](#) [CLH07\(TE16L,Q\)](#) [CLH03\(TE16L,Q\)](#) [1N5395-TP](#) [UES1302](#) [ACGRC307-HF](#) [ACEFC304-HF](#) [DZ-](#)
[1380](#) [85HFR60](#) [40HFR60](#) [70HF120](#) [85HFR80](#) [SCF7500](#) [SM100](#) [ACGRA4001-HF](#) [SKN70/08](#) [NTE5819](#) [NTE5827](#) [NTE5828](#) [NTE5911](#)
[NTE5915](#) [NTE6104](#) [NTE6163](#) [NTE6164](#) [NTE6165](#) [NTE6364](#) [TSD3G](#) [SET130312](#) [NRVUS110VT3G](#) [UES1106](#) [UES1306](#)
[NRVUS240VT3G](#) [D5FE60-5063](#) [R4000GPS-TP](#) [D4015L56TP](#) [UES1306HR2](#) [FX20K120](#) [D20XB60-7101](#)